



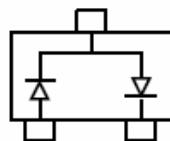
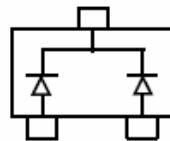
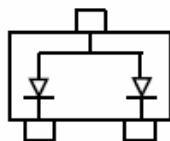
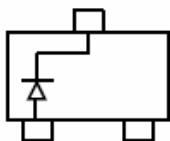
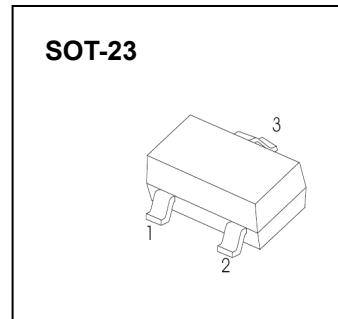
JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOT-23 Plastic-Encapsulate Diodes

MMBD4148A/SE/CC/CA SWITCHING DIODE

FEATURES

- Fast Switching Speed
- For General Purpose Switching Applications
- High Conductance



MARKING:

MMBD4148A:5H

MMBD4148CA :D6

MMBD4148CC :D5

MMBD4148SE :D4

Maximum Ratings @Ta=25°C

Parameter	Symbol	Limit		Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	100		V
Peak Repetitive Peak Reverse Voltage	V _{RRM}			
Working Peak Reverse Voltage	V _{RWM}	100		V
DC Blocking Voltage	V _R			
RMS Reverse Voltage	V _{R(RMS)}	53		V
Forward Continuous Current	I _{FM}	300		mA
Average Rectified Output Current	I _O	200		mA
Peak Forward Surge Current @t=1.0μs @ t=1.0s	I _{FSM}	2.0 1.0		A
Power Dissipation	P _D	350		mW
Thermal Resistance Junction to Ambient	R _{θJA}	357		°C/W
Junction Temperature	T _j	150		°C
Storage Temperature	T _{STG}	-55~+150		°C

Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Reverse breakdown voltage	V _{(BR) 1}	100			V	I _R =100μA
	V _{(BR) 2}	75			V	I _R =5μA
Forward voltage	V _F			1	V	I _F =10mA
Reverse current	I _{R1}			5	μA	V _R =75V
	I _{R2}			25	nA	V _R =25V
Capacitance between terminals	C _T			4	pF	V _R =0V,f=1MHz
Reverse recovery time	t _{rr}			4	ns	I _F =I _R =10mA, V _R =6V, I _{rr} =0.1XI _R ,R _L =100Ω

Typical Characteristics

MMBD4148A

